

April 2016

40V DUAL NPN SMALL SIGNAL TRANSISTOR IN SOT363

Features

- $BV_{CEO} > 40V$
- **Epitaxial Planar Die Construction**
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Complementary PNP Type: MMDT2907A
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

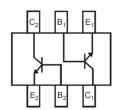
Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.006 grams (Approximate)

SOT363



Top View



Device Schematic Top View

Ordering Information (Note 4)

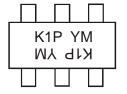
Product	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
MMDT2222A-7-F	Active	AEC-Q101	K1P	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

SOT363



K1P = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: D = 2016) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

<u> </u>												
Year	2013	1	2014	2015		2016	2017	,	2018	2019		2020
Code	А		В	С		D	E		F	G		Н
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	75	V
Collector-Emitter Voltage	V_{CEO}	40	V
Emitter-Base Voltage	V_{EBO}	6.0	V
Continuous Collector Current	Ic	600	mA

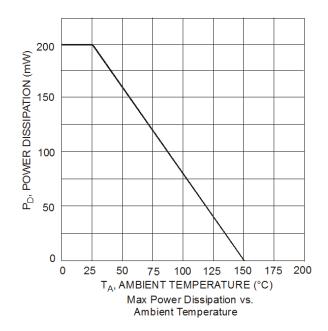
Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_{D}	200	mW
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Thermal Characteristic and Derating Information



^{5.} For the device mounted on minimum recommended pad layout FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

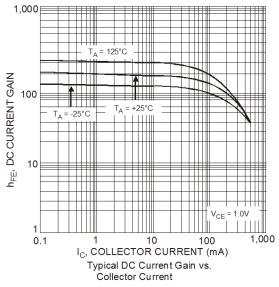
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS					
Collector-Base Breakdown Voltage	BV_{CBO}	75	_	V	$I_C = 10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage (Note 7)	BV_{CEO}	40	_	V	$I_C = 10 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	6.0	_	V	$I_E = 100 \mu A, I_C = 0$
Collector-Base Cut-Off Current	I _{CBO}		10	nA	$V_{CB} = 60V, I_E = 0$
	ICBO			μA	$V_{CB} = 60V$, $I_E = 0$, $T_A = +150$ °C
Collector Cut-Off Current	I _{CEX}	_	10	nA	$V_{CE} = 60V$, $V_{BE(OFF)} = 3.0V$
Emitter-Base Cut-Off Current	I _{EBO}	_	10	nA	$V_{EB} = 3V, I_{C} = 0$
Base Cutoff Current	I_{BL}	_	20	nA	$V_{CE} = 60V$, $V_{BE(OFF)} = 3.0V$
ON CHARACTERISTICS (Note 7)			ı	1	
		35	_		$I_C = 100\mu A, V_{CE} = 10V$
		50	_		$I_C = 1.0 \text{mA}, V_{CE} = 10 \text{V}$
		75	_		$I_C = 10mA, V_{CE} = 10V$
DC Current Gain	h _{FE}	100	300	_	$I_C = 150 \text{mA}, V_{CE} = 10 \text{V}$
		40	_		$I_C = 500 \text{mA}, V_{CE} = 10 \text{V}$
		50 35	_		$I_C = 10 \text{mA}, V_{CE} = 10 \text{V}, T_A = -55 ^{\circ}\text{C}$
		30	_		$I_C = 150 \text{mA}, V_{CE} = 1.0 \text{V}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		0.3	V	$I_C = 150 \text{mA}, I_B = 15 \text{mA}$
Conector-Emitter Saturation Voltage	VCE(SAT)		1.0	V	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	0.6	1.2	V	$I_C = 150 \text{mA}, I_B = 15 \text{mA}$
Ŭ	VBE(SAT)	_	2.0	V	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$
SMALL SIGNAL CHARACTERISTICS			1	1	
Output Capacitance	C _{obo}		8.0	pF	$V_{CB} = 10V, f = 1.0MHz, I_{E} = 0$
Input Capacitance	C _{ibo}	_	25	pF	$V_{EB} = 0.5V, f = 1.0MHz, I_{C} = 0$
Current Gain-Bandwidth Product	f _T	300	_	MHz	$V_{CE} = 20V, I_{C} = 20mA,$ f = 100MHz
Noise Figure	N _F		4.0	dB	$V_{CE} = 10V, I_{C} = 100\mu A,$ $R_{S} = 1.0k\Omega, f = 1.0kHz$
SWITCHING CHARACTERISTICS				l	115 - 1.0A12, 1 = 1.0A112
Delay Time	t _D	_	10	ns	V _{CC} = 30V, I _C = 150mA,
Rise Time	t _R		25	ns	V _{BE(OFF)} = -0.5V, I _{B1} = 15mA
Storage Time	ts	_	225	ns	Vcc = 30V. Ic = 150mA.
Fall Time	t _F		60	ns	$I_{B1} = I_{B2} = 15 \text{mA}$
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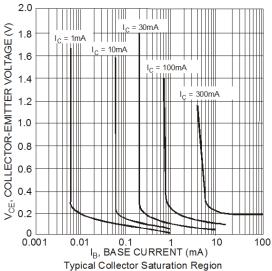
Note:

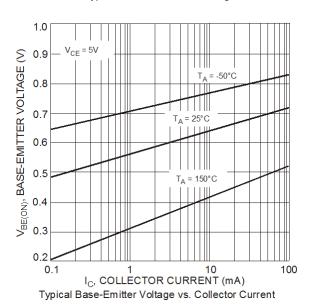
7. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

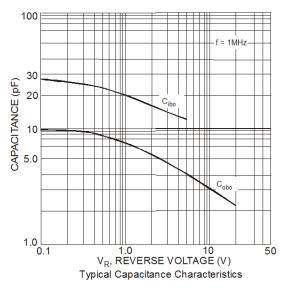


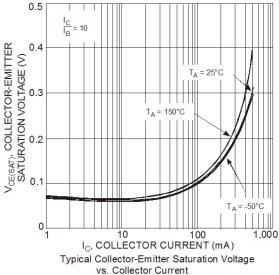
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)









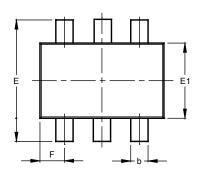


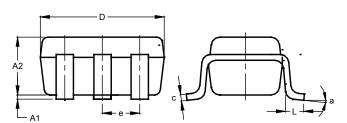


Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363



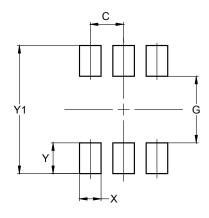


SOT363							
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.90	1.00	1.00				
b	0.10	0.30	0.25				
C	0.10	0.22	0.11				
D	1.80	2.20	2.15				
Е	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
e	0.650 BSC						
F	0.40	0.45	0.425				
١	0.25	0.40	0.30				
а	0°	8°					
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363



Dimensions	Value
Dilliensions	(in mm)
С	0.650
G	1.300
Х	0.420
Υ	0.600
Y1	2 500



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